INTEGRATED CIRCUITS



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Philips Semiconductors

TDA7053A

FEATURES

- DC volume control
- Few external components
- Mute mode
- Thermal protection
- Short-circuit proof
- No switch-on and switch-off clicks
- Good overall stability
- Low power consumption
- Low HF radiation
- ESD protected on all pins.

QUICK REFERENCE DATA

GENERAL DESCRIPTION

The TDA7053A (2×1 W) and TDA7053AT (2×0.5 W) are stereo BTL output amplifiers with DC volume control. The devices are designed for use in TV and monitors, but are also suitable for battery-fed portable recorders and radios.

Missing Current Limiter (MCL)

A MCL protection circuit is built-in. The MCL circuit is activated when the difference in current between the output terminal of each amplifier exceeds 100 mA (typical 300 mA). This level of 100 mA allows for headphone applications (single-ended).

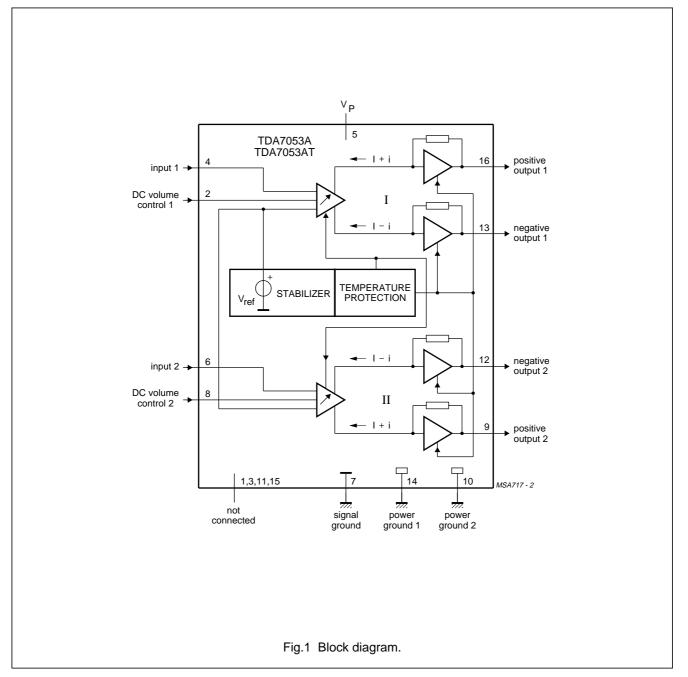
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _P	supply voltage		4.5	-	18	V
Pout	output power	V _P = 6 V				
	TDA7053A	$R_L = 8 \Omega$	0.85	1.0	-	W
	TDA7053AT	$R_L = 16 \Omega$	0.5	0.55	-	W
G _v	voltage gain		39.5	40.5	41.5	dB
G _C	gain control		68.0	73.5	-	dB
I _{q(tot)}	total quiescent current	$V_P = 6 V; R_L = \infty$	-	22	25	mA
THD	total harmonic distortion					
	TDA7053A	$P_{out} = 0.5 W$	-	0.3	1	%
	TDA7053AT	P _{out} = 0.25 W	-	0.3	1	%

ORDERING INFORMATION

TYPE		PACKAGE			
NUMBER	NAME	DESCRIPTION	VERSION		
TDA7053A	DIP16	plastic dual in-line package; 16 leads (300 mil); long body	SOT38-1		
TDA7053AT	SO16	plastic small outline package; 16 leads; body width 7.5 mm	SOT162-1		

TDA7053A

BLOCK DIAGRAM



PINNING

SYMBOL	PIN	DESCRIPTION
n.c.	1	not connected
VC1	2	DC volume control 1
n.c.	3	not connected
V _{I (1)}	4	voltage input 1
V _P	5	positive supply voltage
V _{I (2)}	6	voltage input 2
SGND	7	signal ground
VC2	8	DC volume control 2
OUT2+	9	positive output 2
PGND2	10	power ground 2
n.c.	11	not connected
OUT2-	12	negative output 2
OUT1-	13	negative output 1
PGND1	14	power ground 1
n.c.	15	not connected
OUT1+	16	positive output 1

FUNCTIONAL DESCRIPTION

The TDA7053A and TDA7053AT are stereo output amplifiers with two DC volume control stages, designed for TV and monitors, but also suitable for battery-fed portable recorders and radios.

In conventional DC volume control circuits the control or input stage is AC coupled to the output stage via external capacitors to keep the offset voltage low.

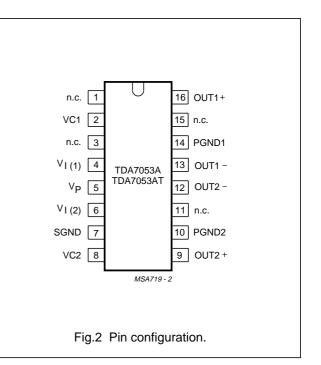
The two DC volume control stages are integrated into the input stages so that no coupling capacitors are required and a low offset voltage is still maintained. The minimum supply voltage also remains low.

The BTL principle offers the following advantages:

- · Lower peak value of the supply current
- The frequency of the ripple on the supply voltage is twice the signal frequency.

Consequently, a reduced power supply with smaller capacitors can be used which results in cost reductions.

TDA7053A



For portable applications there is a trend to decrease the supply voltage, resulting in a reduction of output power at conventional output stages. Using the BTL principle increases the output power.

The maximum gain of the amplifier is fixed at 40.5 dB. The DC volume control stages have a logarithmic control characteristic. Therefore, the total gain can be controlled from +40.5 to -33 dB.

If the DC volume control voltage falls below 0.4 V, the device will switch to the mute mode.

The amplifier is short-circuit protected to ground, V_P and across the load. A thermal protection circuit is also implemented. If the crystal temperature rises above 150 °C the gain will be reduced, thereby reducing the output power.

Special attention is given to switch-on and switch-off clicks, low HF radiation and a good overall stability.

TDA7053A

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _P	supply voltage		_	18	V
I _{ORM}	repetitive peak output current		-	1.25	A
I _{OSM}	non-repetitive peak output current		-	1.5	A
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	TDA7053A		-	2.5	W
	TDA7053AT		-	1.32	W
t _{sc}	short-circuit time		-	1	hr
Vn	input voltage pins 2, 4, 6 and 8		-	5	V
T _{amb}	operating ambient temperature		-40	+85	°C
T _{stg}	storage temperature		-55	+150	°C
T _{vj}	virtual junction temperature		-	+150	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient in free air		
	TDA7053A	50	K/W
	TDA7053AT	95	K/W

Power dissipation

TDA7053A:

Assume V_P = 6 V and R_L = 8 $\Omega.$

The maximum sine wave dissipation is 2×0.9 W = 1.8 W.

The R_{th j-a} of the package is 50 K/W therefore $T_{amb(max)} = 150 - (50 \times 1.8) = 60$ °C.

TDA7053AT:

Assume $V_P = 6 V$ and $R_L = 16 \Omega$.

The maximum sine wave dissipation is 2×0.46 W = 0.92 W.

The R_{th j-a} of the package is 95 K/W therefore $T_{amb(max)} = 150 - (95 \times 0.92) = 62.6$ °C.

TDA7053A

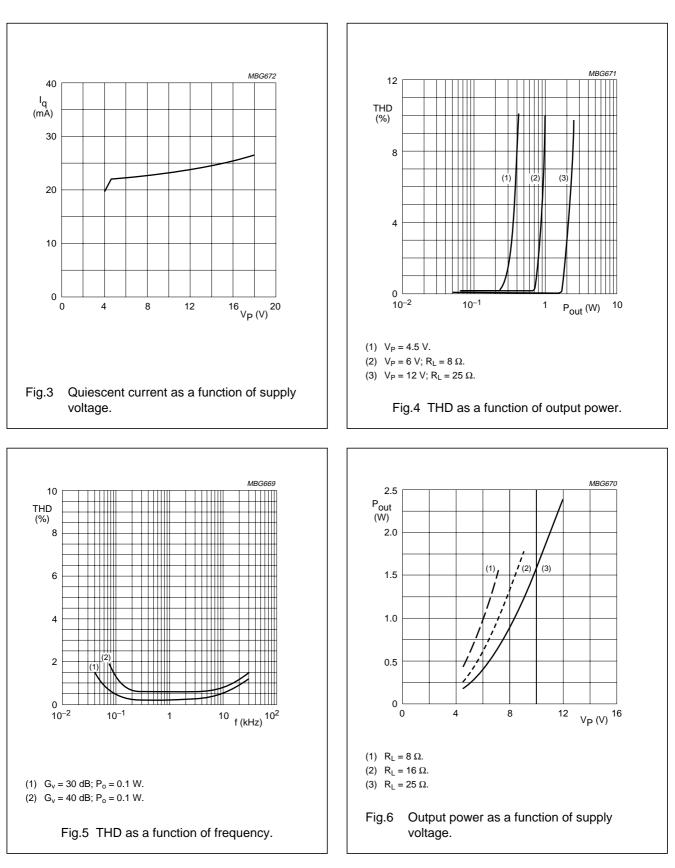
CHARACTERISTICS

 $V_P = 6 \text{ V}$; $T_{amb} = 25 \text{ °C}$; $f_i = 1 \text{ kHz}$; TDA7053A: $R_L = 8 \Omega$; TDA7053AT: $R_L = 16 \Omega$; unless otherwise specified (see Fig.13).

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _P	supply voltage		4.5	-	18	V
I _{q(tot)}	total quiescent current	V _P = 6 V; R _L = ∞; note 1	-	22	25	mA
Maximum ga	ain; V _{2,8} ≥ 1.4 V					
Pout	output power	THD = 10%				
	TDA7053A		1.0	1.1	-	W
	TDA7053AT		0.5	0.55	_	W
THD	total harmonic distortion					
	TDA7053A	P _{out} = 0.5 W	_	0.3	1	%
	TDA7053AT	P _{out} = 0.25 W	_	0.3	1	%
Gv	voltage gain		39.5	40.5	41.5	dB
V _{I(rms)}	input signal handling (RMS value)	G _v = 0 dB; THD < 1%	1	-	-	V
V _{no}	noise output voltage	f _i = 500 kHz; note 2	-	210	-	μV
В	bandwidth	at –1 dB	-	note 3	-	Hz
SVRR	supply voltage ripple rejection	note 4	34	38	-	dB
V _{O(os)}	DC output offset voltage	$ V_{16} - V_{13} $ and $ V_{12} - V_{9} $	-	0	200	mV
Zi	input impedance (pins 4 and 6)		15	20	25	kΩ
α_{cs}	channel separation	$R_{S} = 5 k\Omega$	40	-	-	dB
G _v	channel unbalance	note 5	-	-	1	dB
		$G_1 = 0 dB;$ note 6	-	-	1	dB
Mute positio	on; V _{2,8} = 0.4 V ±30 mV					
Vo	output voltage in mute position	V _i = 1.0 V; note 7	_	30	40	μV
DC volume of	control					
G _C	gain control		68.5	73.5	-	dB
I _{DC}	volume control current	$V_2 = V_8 = 0 V$	-20	-25	-30	μA

Notes

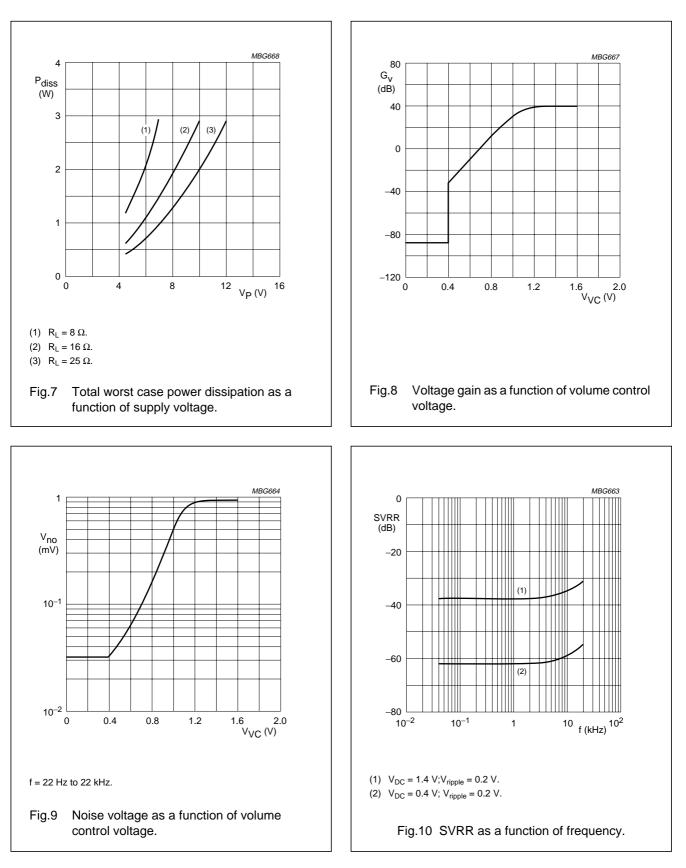
- 1. With a load connected to the outputs the quiescent current will increase, the maximum value of this increase being equal to the DC output offset voltage divided by R_L .
- 2. The noise output voltage (RMS value) at f_i = 500 kHz is measured with R_S = 0 Ω and bandwidth = 5 kHz.
- 3. 20 Hz to 300 kHz (typical).
- 4. The ripple rejection is measured with $R_S = 0 \Omega$ and $f_i = 100$ Hz to 10 kHz. The ripple voltage of 200 mV (RMS value) is applied to the positive supply rail.
- 5. The channel unbalance is measured with $V_{DC1} = V_{DC2}$.
- 6. The channel unbalance at $G_1 = 0$ dB is measured with $V_{DC1} = V_{DC2}$.
- 7. The noise output voltage (RMS value) is measured with $R_S = 5 k\Omega$ unweighted.



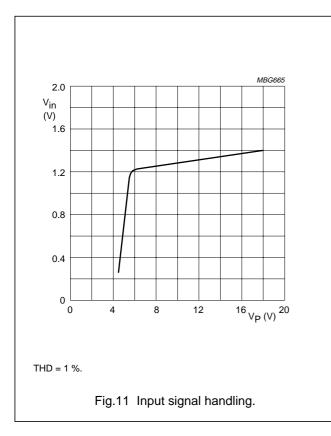
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APPLICATION INFORMATION

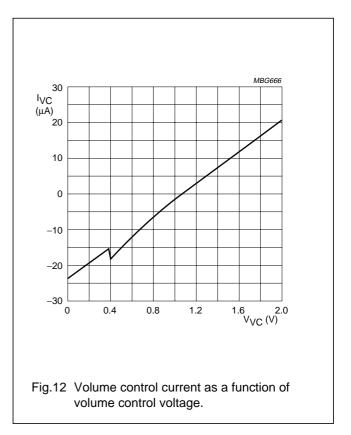
The application diagram is illustrated in Fig.13.

Test conditions

 $\label{eq:Tamb} \begin{array}{l} T_{amb} = 25 \ ^{\circ}C \ \text{unless otherwise specified; } V_{P} = 6 \ \text{V;} \\ V_{DC} = 1.4 \ \text{V;} \ f_{i} = 1 \ \text{kHz; } R_{L} = 8 \ \Omega. \end{array}$

The quiescent current has been measured without load impedance.

The output power as a function of the supply voltage has been measured at THD = 10%. The maximum output power is limited by the maximum power dissipation and the maximum available output current.



The maximum input signal voltage is measured at THD = 1% at the output with a voltage gain of 0 dB.

To avoid instabilities and too high distortion, the input ground and power ground must be separated as far as possible and connected as close as possible to the IC.

The DC volume control can be applied in several ways. Two possible circuits are shown below the main application diagram. The circuits at the control pin will influence the switch-on and switch-off behaviour and the maximum voltage gain.

For single-end applications the output peak current must not exceed 100 mA. At higher output currents the short-circuit protection (MCL) will be active.

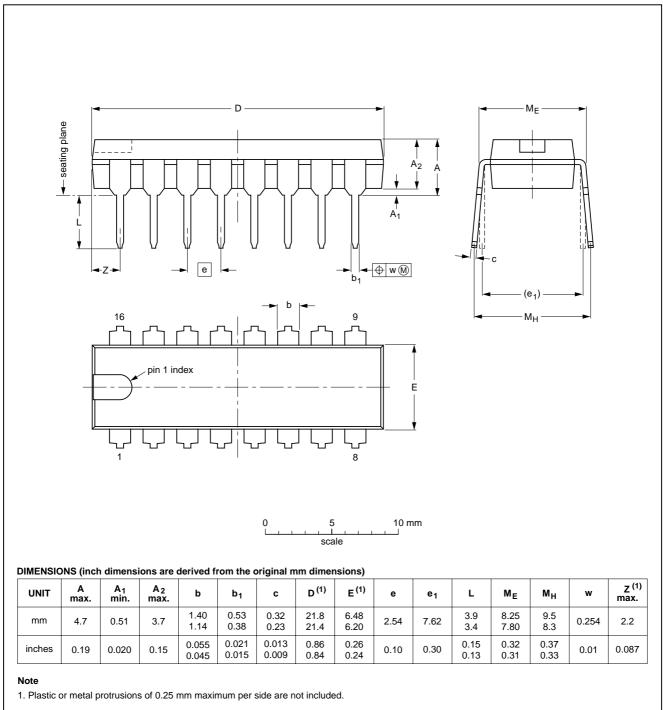
V_P = 6 V ± 100 nF + _____ 220 μF (1) 5 TDA7053A 16 **◄**____ 470 nF input 1 -11 2 (2) $R_s = 5 k\Omega$ I – i 13 TEMPERATURE MCL PROTECTION STABILIZER 12 470 nF **▲**– 6 ╢ input 2 8 (2) l + i DCg volume $R_s = 5 k\Omega$ (\mathcal{H}) $T_{\underline{14}}$. 10 **,** signal ground power ground V_P = 6 V 56 kΩ volume volume control 2, 8 control 2, 8 maximum voltage gain 34 dB maximum voltage gain 40 dB -1 μF 1 MΩ -1 μF 22 kΩ -----MBG673 (1) This capacitor can be omitted if the 220 μF electrolytic capacitor is connected close to pin 5. (2) $R_L = 8 \Omega$. Fig.13 Test and application diagram.

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PACKAGE OUTLINES

DIP16: plastic dual in-line package; 16 leads (300 mil); long body

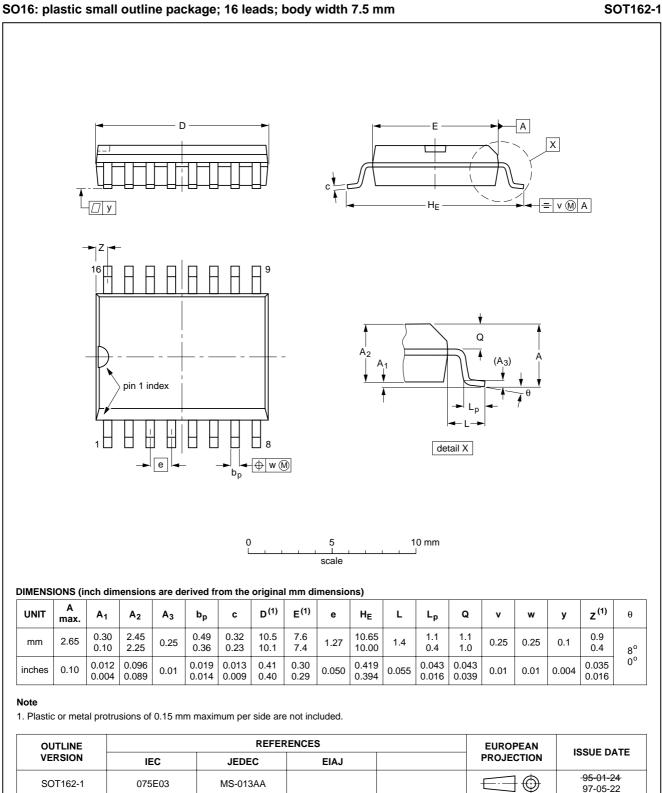


OUTLINE	LINE REFERENCES		EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ	PROJECTION	
SOT38-1	050G09	MO-001AE			92-10-02 95-01-19

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SOLDERING

Introduction

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mounted components are mixed on one printed-circuit board. However, wave soldering is not always suitable for surface mounted ICs, or for printed-circuits with high population densities. In these situations reflow soldering is often used.

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"IC Package Databook"* (order code 9398 652 90011).

DIP

SOLDERING BY DIPPING OR BY WAVE

The maximum permissible temperature of the solder is 260 °C; solder at this temperature must not be in contact with the joint for more than 5 seconds. The total contact time of successive solder waves must not exceed 5 seconds.

The device may be mounted up to the seating plane, but the temperature of the plastic body must not exceed the specified maximum storage temperature ($T_{stg max}$). If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature within the permissible limit.

REPAIRING SOLDERED JOINTS

Apply a low voltage soldering iron (less than 24 V) to the lead(s) of the package, below the seating plane or not more than 2 mm above it. If the temperature of the soldering iron bit is less than $300 \,^{\circ}$ C it may remain in contact for up to 10 seconds. If the bit temperature is between 300 and 400 $^{\circ}$ C, contact may be up to 5 seconds.

SO

REFLOW SOLDERING

Reflow soldering techniques are suitable for all SO packages.

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement. Several techniques exist for reflowing; for example, thermal conduction by heated belt. Dwell times vary between 50 and 300 seconds depending on heating method. Typical reflow temperatures range from 215 to 250 °C.

Preheating is necessary to dry the paste and evaporate the binding agent. Preheating duration: 45 minutes at 45 $^{\circ}$ C.

WAVE SOLDERING

Wave soldering techniques can be used for all SO packages if the following conditions are observed:

- A double-wave (a turbulent wave with high upward pressure followed by a smooth laminar wave) soldering technique should be used.
- The longitudinal axis of the package footprint must be parallel to the solder flow.
- The package footprint must incorporate solder thieves at the downstream end.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Maximum permissible solder temperature is 260 °C, and maximum duration of package immersion in solder is 10 seconds, if cooled to less than 150 °C within 6 seconds. Typical dwell time is 4 seconds at 250 °C.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

REPAIRING SOLDERED JOINTS

Fix the component by first soldering two diagonallyopposite end leads. Use only a low voltage soldering iron (less than 24 V) applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C. When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 °C.

Product specification

Stereo BTL audio output amplifier with DC volume control

TDA7053A

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
more of the limiting values of the device at these or at	accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or may cause permanent damage to the device. These are stress ratings only and operation any other conditions above those given in the Characteristics sections of the specification limiting values for extended periods may affect device reliability.
Application information	

Where application information is given, it is advisory and does not form part of the specification.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

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